General Description he CD4066BM/CD4066BC is a quad bilateral switch in- ended for the transmission or multiplexing of analog or digi- al signals. It is pin-for-pin compatible with CD4016BM/ D4016BC, but has a much lower "ON" resistance, and ON" resistance is relatively constant over the input-signal ange.	eq:stremely low ''OFF'' 0.1 nA (typ.) switch leakage
$\label{eq:constraints} \begin{array}{llllllllllllllllllllllllllllllllllll$	 Applications Analog signal switching/multiplexing Signal gating Squelch control Chopper Modulator/Demodulator Commutating switch Digital signal switching/multiplexing CMOS logic implementation Analog-to-digital/digital-to-analog conversion Digital control of frequency, impedance, phase, and analog-signal-gain

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Order Number CD4066B

CONTROL

RRD-B30M105/Printed in U. S. A.

TL/F/5665-1

OUT/IN

7

₽vss

14 V_{DD}

13 CONTROL A

12 CONTROL D

N/OUT

OUT/IN

OUT/IN

IN/OUT

10

Dual-In-Line Package

SW A

SW D

SW B

Top View

IN/OUT

IN/OUT

CONTROL B

CONTROL C

v_{ss}

OUT/IN _____

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Absolute Maximum Ratings (Notes 1 & 2) If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Recommended Operating Conditions (Note 2)

Supply Voltage (V _{DD})	3V to 15V
Input Voltage (V _{IN})	0V to V _{DD}
Operating Temperature Range (T _A)	
CD4066BM	-55°C to +125°C
CD4066BC	-40°C to +85°C

DC Electrical Characteristics CD4066BM (Note 2)

Symbol	Parameter	Conditions	-55°C			+ 25°C		+ 1	Unite	
Symbol	Falameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Units
I _{DD}	Quiescent Device Current	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		0.25 0.5 1.0		0.01 0.01 0.01	0.25 0.5 1.0		7.5 15 30	μΑ μΑ μΑ
SIGNAL IN	NPUTS AND OUTPUTS									
R _{ON}	"ON" Resistance			800 310 200		270 120 80	1050 400 240		1300 550 320	Ω Ω Ω
ΔR _{ON}	Δ"ON" Resistance Between any 2 of 4 Switches	$ \begin{array}{l} {\sf R}_L \!=\! 10 \; {\sf k} \Omega \; to \; \frac{{\sf V}_{DD} \!-\! {\sf V}_{SS}}{2} \\ {\sf V}_C \!=\! {\sf V}_{DD}, \; {\sf V}_{IS} \!=\! {\sf V}_{SS} \; to \; {\sf V}_{DD} \\ {\sf V}_{DD} \!=\! 10{\sf V} \\ {\sf V}_{DD} \!=\! 15{\sf V} \end{array} $				10 5				Ω Ω
I _{IS}	Input or Output Leakage Switch "OFF"	$V_{C}=0$ $V_{IS}=15V$ and 0V, $V_{OS}=0V$ and 15V		±50		±0.1	±50		±500	nA
CONTROL	LINPUTS									
VILC	Low Level Input Voltage	$\label{eq:VIS} \begin{array}{l} V_{IS}\!=\!V_{SS} \text{ and } V_{DD} \\ V_{OS}\!=\!V_{DD} \text{ and } V_{SS} \\ I_{IS}\!=\!\pm10 \ \mu\text{A} \\ V_{DD}\!=\!5V \\ V_{DD}\!=\!10V \\ V_{DD}\!=\!15V \end{array}$		1.5 3.0 4.0		2.25 4.5 6.75	1.5 3.0 4.0		1.5 3.0 4.0	V V V
V _{IHC}	High Level Input Voltage	$V_{DD} = 5V$ $V_{DD} = 10V$ (see note 6) $V_{DD} = 15V$	3.5 7.0 11.0		3.5 7.0 11.0	2.75 5.5 8.25		3.5 7.0 11.0		V V V
I _{IN}	Input Current	$V_{DD} - V_{SS} = 15V$ $V_{DD} \ge V_{IS} \ge V_{SS}$ $V_{DD} \ge V_C \ge V_{SS}$		±0.1		±10 ⁻⁵	±0.1		±1.0	μΑ

DC Electrical Characteristics CD4066BC (Note 2)

Symbol	Parameter	Conditions	_40°C			+ 25°C		+ 8	Units	
Cymbol	rarameter		Min	Max	Min	Тур	Max	Min	Max	enne
IDD	Quiescent Device Current	V _{DD} =5V		1.0		0.01	1.0		7.5	μΑ
		V _{DD} =10V		2.0		0.01	2.0		15	μΑ
		$V_{DD} = 15V$		4.0		0.01	4.0		30	μΑ

Symbol	Daramatar	Conditions		-4	40°C	+ 25°C					+ 85°C	Unita
Symbol	Parameter		bilations	Min	Max	Min	Т	ур	Max	Mir	n Max	
SIGNAL II	NPUTS AND OUTPUTS											
R _{ON}	"ON" Resistance	R _L =10 kΩ	to $\frac{V_{DD} - V_{SS}}{2}$									
		$V_{\rm C} = V_{\rm DD}$	V_{SS} to V_{DD}		050				1050		100	
		$V_{DD} = 5V$			850		2	70 20	1050		1200	
		$V_{DD} = 10V$ $V_{DD} = 15V$			210		8	20 30	240		300	Ω
	Δ"ON" Resistance	 Ri = 10 kΩ	to $\frac{V_{DD} - V_{SS}}{V_{DD} - V_{SS}}$									
011	Between Any 2 of $V_{CC} =$		$V_{IS} = V_{SS}$ to V_{DD}									
	4 Switches	$V_{DD} = 10V$					1	0				Ω
		V _{DD} =15V						5				Ω
I _{IS}	Input or Output Leakage Switch "OFF"	V _C =0			±50		_ ±	0.1	±50		±20	0 nA
CONTRO	LINPUTS											
VILC	Low Level Input Voltage	V _{IS} =V _{SS} a	and V _{DD}									
		$V_{OS} = V_{DD}$ and V_{SS}										
		ון s= ± וטµ ער=5V = חח	A		1.5		2.	25	1.5		1.5	v
		V _{DD} =10V			3.0		4	.5	3.0		3.0	V
		V _{DD} =15V			4.0		6.	75	4.0		4.0	V
VIHC	High Level Input Voltage	$V_{DD} = 5V$ $V_{DD} = 10V$ (See note 6) $V_{DD} = 15V$		3.5		3.5	2.	75		3.5	5	
				11.0		11.0	8.	.5 25		11.	0	V
IIN	Input Current	$V_{DD} - V_{SS} = 15V$ $V_{DD} \ge V_{IS} \ge V_{SS}$			±0.3		±1	0-5	±0.3		±1.0) μΑ
		VDZ≤VC≥	VSS									
AC E	Electrical Charac	teristic	S* T _A =25°C, t _r =1	t _f =20 r	ns and V	/ _{SS} =0\	/ unle	ess ot	herwise	note	d	
Symbo	Paramete	r	Conditions					Mi	n T	ур	Max	Units
t _{PHL} , t _{PL}	_H Propagation Delay T	ime Signal	$V_{C} = V_{DD}$, $C_{L} = 50$ pF, (<i>Figure 1</i>)									
	Input to Signal Outpu	ut	$R_L = 200k$						25	55	ne	
			$V_{DD} = 10V$							15	35	ns
		V _{DD} =15V							10	25	ns	
t _{PZH} , t _{P2}	ZL Propagation Delay T	Propagation Delay Time			, (Figure	<i>s 2</i> and	1 <i>3</i>)					
	Control Input to Sign	Control Input to Signal		$V_{DD} = 5V$							125 60	ns
	Logical Level		$V_{DD} = 15V$								50	ns
t _{PHZ} , t _{PLZ} Propagation Delay Time			$R_L = 1.0 \text{ k}\Omega, C_L =$	= 50 pF	, (Figure	s 2 and	1 <i>3</i>)					
	Control Input to Sign	al	V _{DD} =5V								125	ns
	Output Logical Level	to	$V_{DD} = 10V$								60 50	ns
	Sine Wave Distortion	Sine Wave Distortion		$V_{\rm C} = V_{\rm DD} = 5V, V_{\rm SS} = -5V$).1	00	%
					$R_L = 10 \text{ k}\Omega, V_{IS} = 5V_{p-p}, f = 1 \text{ kHz},$							
	Frequency Response	a-Switch	(Figure 4)	/00	- 5V					10		мн⊸
	"ON" (Frequency at	-3 dB)	$R_{L} = 1 k\Omega, V_{IS} =$	' SS — — 5V _{p-n} ,	50,					+0		
			20 Log ₁₀ V _{OS} /V _{OS} (1 kHz)-dB,									
			(Figure 4)									

AC El	AC Electrical Characteristics [*] (Continued) $T_A = 25^{\circ}C$, $t_r = t_f = 20$ ns and $V_{SS} = 0V$ unless otherwise noted										
Symbol	Parameter	Conditions	Min	Тур	Мах	Units					
	Feedthrough — Switch "OFF" (Frequency at -50 dB)	$V_{DD} = 5.0V, V_{CC} = V_{SS} = -5.0V,$ $R_L = 1 k\Omega, V_{IS} = 5.0V_{p-p}, 20 Log_{10},$ $V_{OS}/V_{IS} = -50 dB, (Figure 4)$		1.25							
	Crosstalk Between Any Two Switches (Frequency at -50 dB)	$V_{DD} = V_{C(A)} = 5.0V; V_{SS} = V_{C(B)} = 5.0V, R_{L} 1 k\Omega, V_{IS(A)} = 5.0 V_{p-p}, 20 Log_{10}, V_{OS(B)} / V_{IS(A)} = -50 dB (Figure 5)$		0.9		MHz					
	Crosstalk; Control Input to Signal Output	$V_{DD}^{(r)} = 10V$, $R_L^{(r)} = 10 k\Omega$, $R_{IN}^{(r)} = 1.0 k\Omega$, $V_{CC}^{(r)} = 10V$ Square Wave, $C_L^{(r)} = 50 \text{ pF}$ (Figure 6)		150		mV _{p-p}					
	Maximum Control Input	$R_L = 1.0 \text{ k}\Omega, C_L = 50 \text{ pF}, (Figure 7)$ $V_{OS(f)} = \frac{1}{2} V_{OS}(1.0 \text{ kHz})$									
		$V_{DD} = 5.0V$ $V_{DD} = 10V$		6.0 8.0		MHz MHz					
		V _{DD} =15V		8.5		MHz					
C _{IS}	Signal Input Capacitance			8.0		pF					
C _{OS}	Signal Output Capacitance	V _{DD} =10V		8.0		pF					
C _{IOS}	Feedthrough Capacitance	V _C =0V		0.5		pF					
CIN	Control Input Capacitance			5.0	7.5	pF					

*AC Parameters are guaranteed by DC correlated testing.

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.

Note 2: V_{SS}=0V unless otherwise specified.

Note 3: These devices should not be connected to circuits with the power "ON".

Note 4: In all cases, there is approximately 5 pF of probe and jig capacitance in the output; however, this capacitance is included in C_L wherever it is specified. Note 5: V_{IS} is the voltage at the in/out pin and V_{OS} is the voltage at the out/in pin. V_C is the voltage at the control input.

Note 5. Vis the voltage at the involt pin and vis is the voltage at the out in pin. Vis the voltage at the control nipt

Note 6: Conditions for V_{IHC}: a) V_{IS}=V_{DD}, I_{OS}=standard B series I_{OH} b) V_{IS}=0V, I_{OL}=standard B series I_{OL}.

AC Test Circuits and Switching Time Waveforms







Special Considerations

In applications where separate power sources are used to drive V_{DD} and the signal input, the V_{DD} current capability should exceed $V_{DD}/R_{\rm L}$ ($R_{\rm L}$ = effective external load of the 4 CD4066BM/CD4066BC bilateral switches). This provision avoids any permanent current flow or clamp action of the V_{DD} supply when power is applied or removed from CD4066BM/CD4066BC.

In certain applications, the external load-resistor current may include both V_{DD} and signal-line components. To avoid

drawing V_{DD} current when switch current flows into terminals 1, 4, 8 or 11, the voltage drop across the bidirectional switch must not exceed 0.6V at $T_A{\leq}25^\circ\text{C}$, or 0.4V at $T_A{>}25^\circ\text{C}$ (calculated from R_{ON} values shown).

No V_{DD} current will flow through ${\rm R}_{\rm L}$ if the switch current flows into terminals 2, 3, 9 or 10.





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